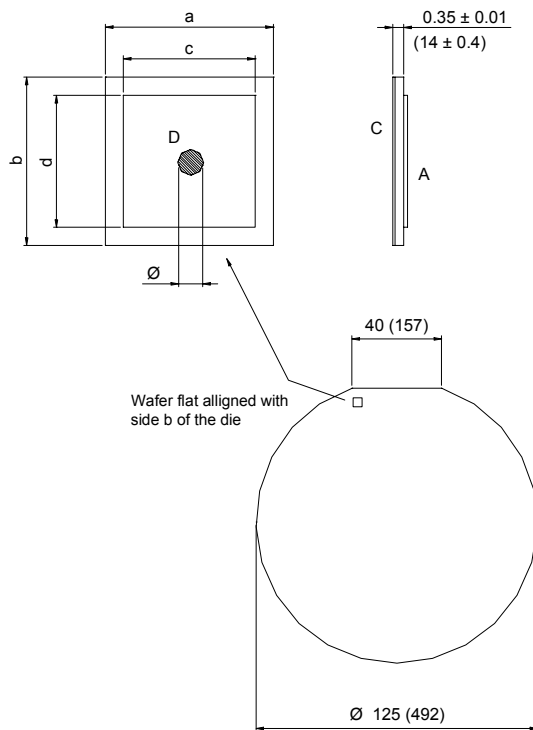


SCHOTTKY DIE 105 x 105 mils



NOTES:

1. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS (MILS).
2. CONTROLLING DIMENSION: (MILS).
3. DIMENSIONS AND TOLERANCES:
 - $a = 2.67 + 0, - 0.01$
(105 $\pm$ 0, - 0.4)
 - $b = 2.67 + 0, - 0.01$
(105 $\pm$ 0, - 0.4)
 - $c = 2.51 + 0, - 0.01$
(99 $\pm$ 0, - 0.4)
 - $d = 2.51 + 0, - 0.01$
(99 $\pm$ 0, - 0.4)
 - $\varnothing = 1 \pm 0.15$
(40 $\pm$ 6)
4. LETTER DESIGNATION:
 - A = Anode (Top Metal)
 - C = Cathode (Back Metal)
 - D = Reject Ink Dot (only on non-conforming dies)
5. SAWING:
 - Recommended Blade
 - SEMITEC S1025 QS00 Blade
 - Sawing Street
 - 0.05 $\pm$ 0, - 0.005
 - (2 $\pm$ 0, - 0.2)

NOT TO SCALE

NOTE: 10 mils die thickness is available on specific request only.
Contact factory for information.

Electrical Characteristics

Device #	T _J Max. (°C)	V _R (V)	Typ. I _R @ 25°C (μA)	Typ. I _R @ 125°C (mA)	Max. V _F @ I _F (V)	Package Style
SC100R015x5x	125	15	n.a. contact factory			
SC100S020x5x	150	20	n.a. contact factory			
SC100S030x5x	150	30	n.a. contact factory			
SC100S045x5x	150	45	120	55	0.76 @ 30A	TO-220
SC100S060x5x	150	60	n.a. contact factory			
SC100H045x5x	175	45	n.a. contact factory			
SC100H100x5x	175	100	7	4.5	0.95 @ 20A	TO-220
SC100H150x5x	175	150	n.a. contact factory			

Mechanical Data

Device #		Metal Thickness Front Metal			Metal Thickness Back Metal		
SC100xxxxA5x	Wire Bondable	–	Al 30 kÅ	–	Cr 1 kÅ	Ni 2 kÅ	Ag 3 kÅ
SC100xxxxS5x	Solderable	Ti 2 kÅ	Ni 1 kÅ	Ag 35 kÅ	Cr 1 kÅ	Ni 2 kÅ	Ag 3 kÅ

Recommended Storage Environment: Store in original container, in dessicated nitrogen, with no contamination.

Shelf life for parts stored in above condition is 2 years.

If the storage is done in normal atmosphere shelf life is reduced to six months.

Packaging

Device #	Description	Minimum Order Quantity Die in Sale Package
SC100xxxxx5B	Inked Probed Unsawn Wafer (Wafer in Box)	1400
SC100xxxxx5R	Probed Die in Tape & Reel	8,000
SC100xxxxx5P	Probed Die in Waffle Pack	1400
SC100xxxxx5F	Inked Probed Sawn Wafer on Film	1400

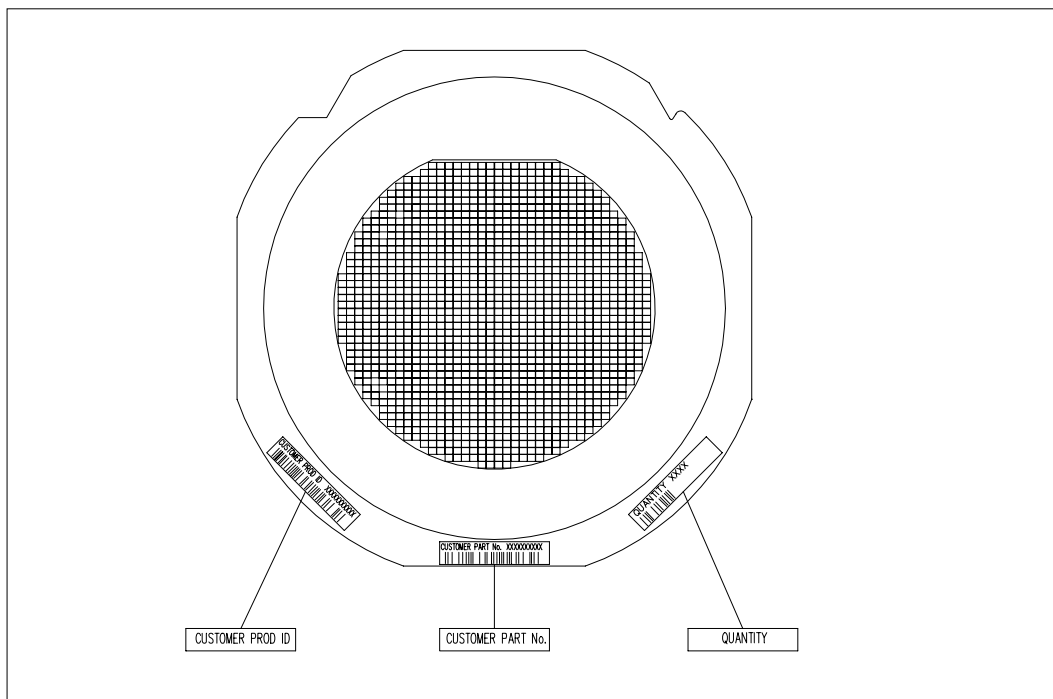
Ordering Information Table

Device Code						
1	2	3	4	5	6	7
SC	100	H	150	A	5	B

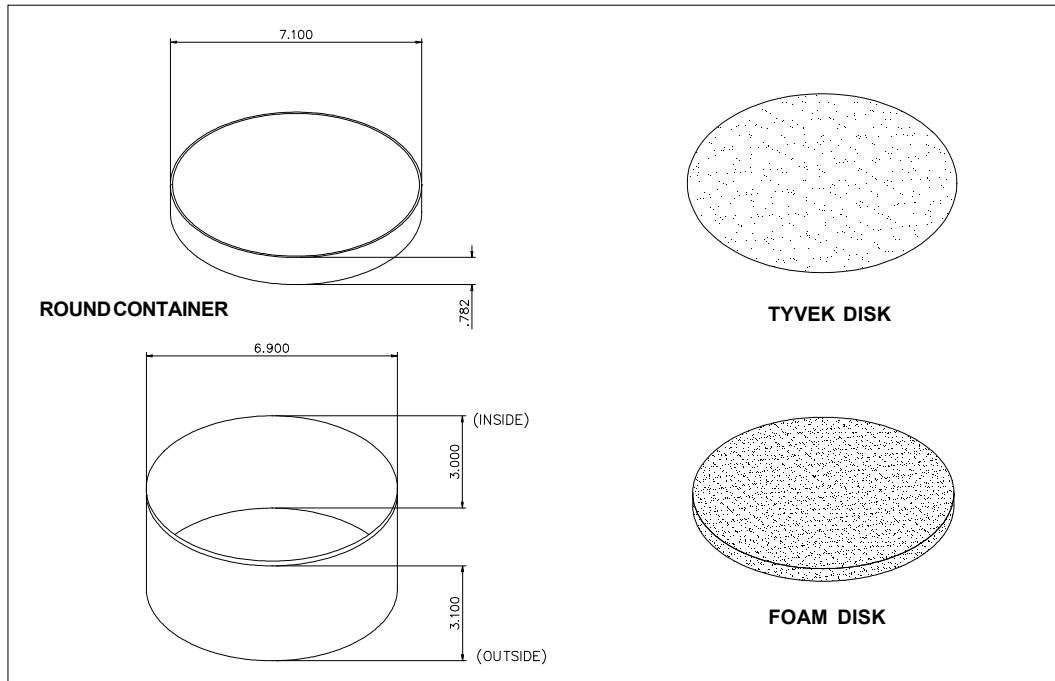
1	- Schottky Die
2	- Chip Dimension in Mils
3	- Process (see Electrical Characteristics Table)
4	- Voltage code: Code = V_{RRM}
5	- Chip surface metallization (see Mechanical Data Table)
6	- Wafer Diameter in inches
7	- Packaging (see Packaging Table)

H = 830 Process
R = OR'ing Process
S = Standard Process

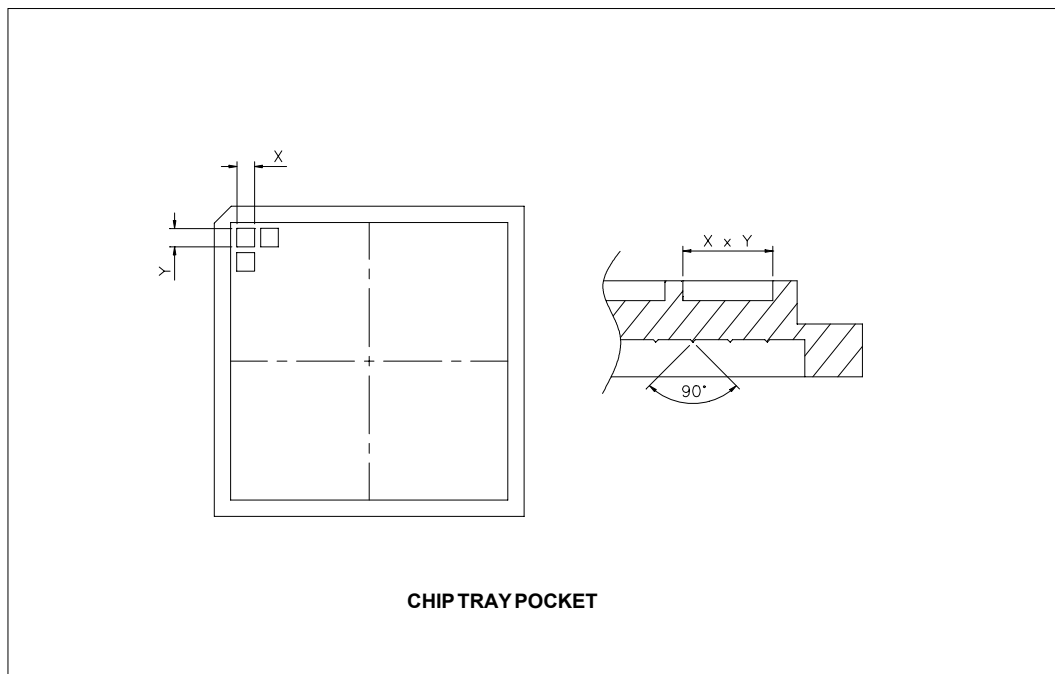
Wafer on Film



Wafer in Box



Die in Waffle Pack



International
IOR Rectifier

WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245 U.S.A. Tel: (310) 322 3331. Fax: (310) 322 3332.
EUROPEAN HEADQUARTERS: Hurst Green, Oxted, Surrey RH8 9BB, U.K. Tel: ++ 44 1883 732020. Fax: ++ 44 1883 733408.
IR CANADA: 15 Lincoln Court, Brampton, Markham, Ontario L6T3Z2. Tel: (905) 453 2200. Fax: (905) 475 8801.
IR GERMANY: Saalburgstrasse 157, 61350 Bad Homburg. Tel: ++ 49 6172 96590. Fax: ++ 49 6172 965933.
IR ITALY: Via Liguria 49, 10071 Borgaro, Torino. Tel: ++ 39 11 4510111. Fax: ++ 39 11 4510220.
IR FAR EAST: K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo, Japan 171. Tel: 81 3 3983 0086.
IR SOUTHEAST ASIA: 1 Kim Seng Promenade, Great World City West Tower, 13-11, Singapore 237994. Tel: ++ 65 838 4630.
IR TAIWAN: 16 Fl. Suite D.207, Sec. 2, Tun Haw South Road, Taipei, 10673, Taiwan. Tel: 886 2 2377 9936.

<http://www.irf.com>

Fax-On-Demand: +44 1883 733420

Data and specifications subject to change without notice.